# BHG9N05TSJ

# **Protected Power MOSFET**

## 2.6 A, 52 V, N–Channel, Logic Level, Clamped MOSFET w/ ESD Protection

#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise specified)

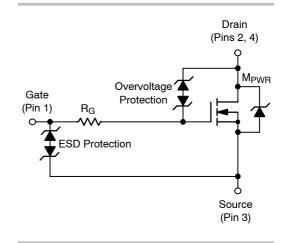
Rating	Symbol	Value	Unit
Drain-to-Source Voltage Internally Clamped	V <sub>DSS</sub>	52–59	V
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	±15	V
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C
Electro-Static Discharge Capability (HBM) (MM)	ESD	5000 500	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

## NIC9N05TS1

MOSFET ELECTRICAL CHARACTERISTICS (1	$_{\rm J}$ = 25°C unless otherwise specified) (Note 1)
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一句"NICONOTISTICALLY"的CENTRICS (1)=250 Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					•
Drain-to-Source Breakdown Voltage (V <sub>GS</sub> = 0 V, I <sub>D</sub> = 1.0 mA, T <sub>J</sub> = 25°C)	V <sub>(BR)DSS</sub>	52	55	59	V
Zero Gate Voltage Drain Current $(V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V})$	I <sub>DSS</sub>			10	μA
$ \begin{array}{l} \mbox{Gate-Body Leakage Current} \\ (V_{GS}=\pm 8 \mbox{ V, } V_{DS}=0 \mbox{ V)} \\ (V_{GS}=\pm 14 \mbox{ V, } V_{DS}=0 \mbox{ V)} \end{array} $	I <sub>GSS</sub>		±22	±10	μA
ON CHARACTERISTICS				•	
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 100 \ \mu\text{A})$	V <sub>GS(th)</sub>	1.3	1.75	2.5	V
$      Static Drain-to-Source On-Resistance \\ (V_{GS} = 3.5 V, I_D = 0.6 A) \\ (V_{GS} = 4.0 V, I_D = 1.5 A) \\ (V_{GS} = 10 V, I_D = 2.6 A) $	R <sub>DS(on)</sub>		190 165 107	380 200 125	mΩ
SOURCE-DRAIN DIODE CHARACTERISTICS					

Forward On-Voltage	$I_{S} = 2.6 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$ $I_{S} = 2.6 \text{ A}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125^{\circ}\text{C}$	V <sub>SD</sub>		0.81 0.66	1.5	V	
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1. Wafers tested prior to sawing.

### **ORDERING INFORMATION**

Device	Shipping	
NIC9N05TS1	5000 / Reel	

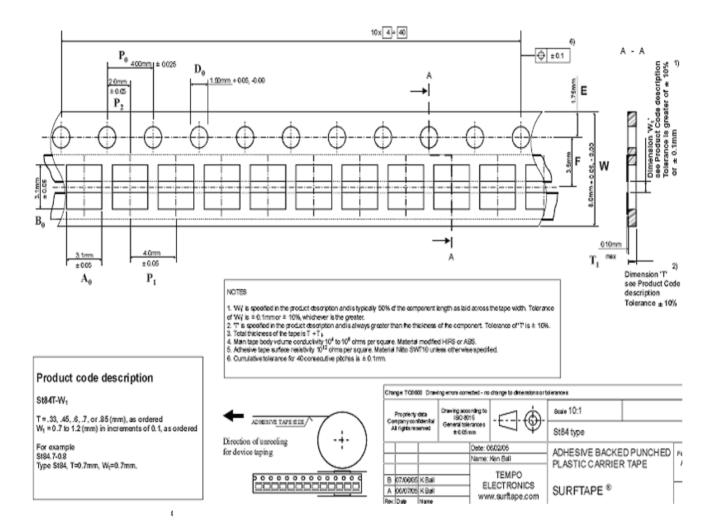
### NIC9N05TS1

## 查询"NIC9N05TS1"供应商

Layout view of the die in reel

Orientation A





查询"NIC9N05TS1"供应商

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